

# General purpose amplification (–12V, –1.5A)

## QST8

### ●Application

Low frequency amplifier

Driver

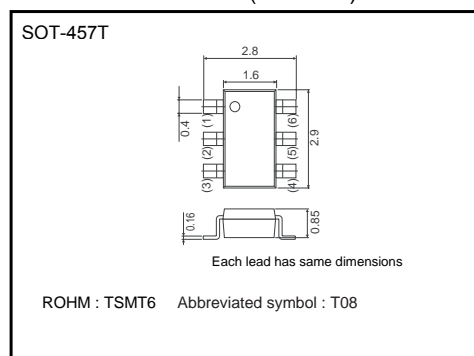
### ●Features

- 1) A collector current is large.
- 2) Collector saturation voltage is low.

$V_{CE(sat)}$  : max. –200mV

At  $I_c = -500\text{mA}$  /  $I_B = -25\text{mA}$

### ●External dimensions (Unit : mm)



### ●Absolute maximum ratings (Ta=25°C)

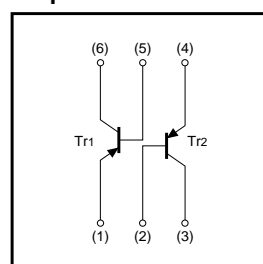
Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CB0}$	–15	V
Collector-emitter voltage	$V_{CE0}$	–12	V
Emitter-base voltage	$V_{EB0}$	–6	V
Collector current	$I_c$	–1.5	A
	$I_{CP}$	–3	A *1
Power dissipation	$P_c$	500	mW/TOTAL *2
		1.25	W/TOTAL *3
		0.9	W/ELEMENT *3
Junction temperature	$T_j$	150	°C
Range of storage temperature	$T_{stg}$	–55 to +150	°C

\*1 Single pulse,  $P_w=1\text{ms}$

\*2 Each Terminal Mounted on a Recommended

\*3 Mounted on a 25mm×25mm×1.0.8mm ceramic substrate

### ●Equivalent circuit



### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CB0}$	–15	–	–	V	$I_c = -10\mu\text{A}$
Collector-emitter breakdown voltage	$BV_{CE0}$	–12	–	–	V	$I_c = -1\text{mA}$
Emitter-base breakdown voltage	$BV_{EB0}$	–6	–	–	V	$I_E = -10\mu\text{A}$
Collector cutoff current	$I_{CB0}$	–	–	–100	nA	$V_{CB} = -15\text{V}$
Emitter cutoff current	$I_{EB0}$	–	–	–100	nA	$V_{EB} = -6\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$	–	–85	–200	mV	$I_c = -500\text{mA}$ , $I_B = -25\text{mA}$
DC current gain	$h_{FE}$	270	–	680	–	$V_{CE} = -2\text{V}$ , $I_c = -200\text{mA}$ *
Transition frequency	$f_T$	–	400	–	MHz	$V_{CE} = -2\text{V}$ , $I_E = 200\text{mA}$ , $f = 100\text{MHz}$ *
Corrector output capacitance	$C_{ob}$	–	12	–	pF	$V_{CB} = -10\text{V}$ , $I_E = 0\text{A}$ , $f = 1\text{MHz}$

\*Pulsed

Transistors

●Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	3000
QST8		○

●Electrical characteristic curves

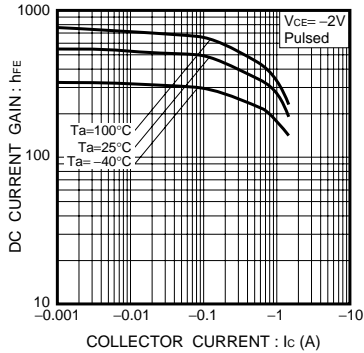


Fig.1 DC current gain vs. collector current

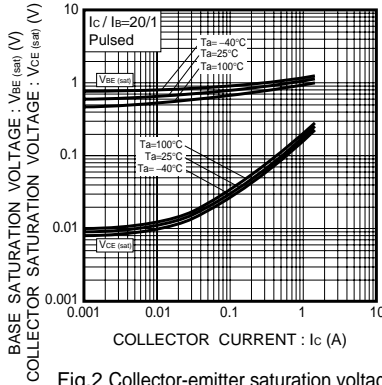


Fig.2 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current

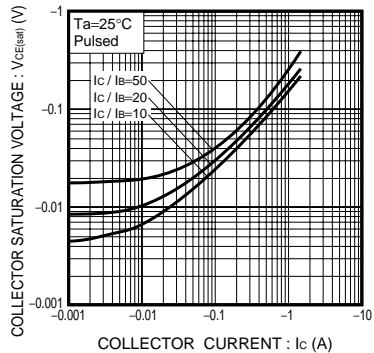


Fig.3 Collector-emitter saturation voltage vs. collector current

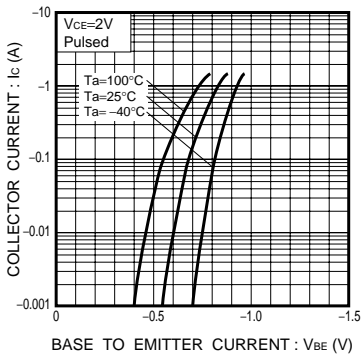


Fig.4 Grounded emitter propagation characteristics

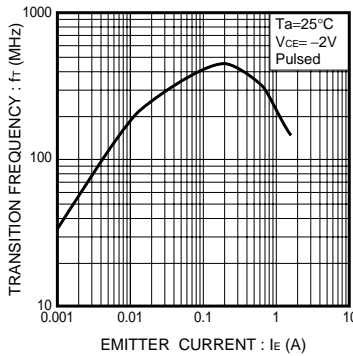


Fig.5 Gain bandwidth product vs. emitter current

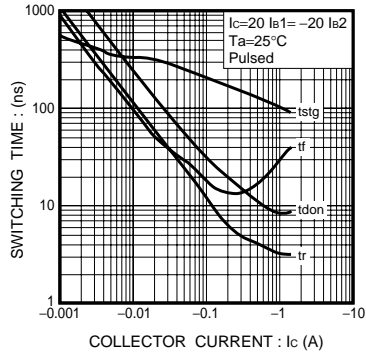


Fig.6 Switching time

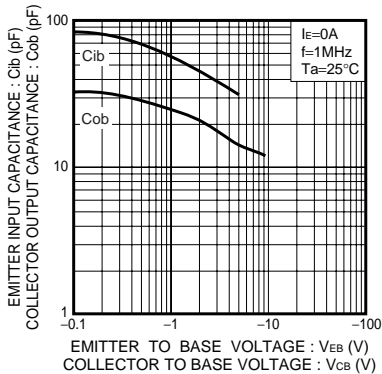


Fig.7 Collector output capacitance vs. collector-base voltage  
Emitter input capacitance vs. emitter-base voltage

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